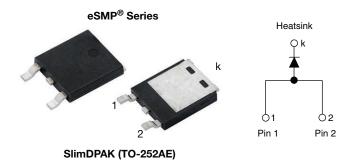
VS-6EVL06HM3

Vishay Semiconductors

Ultralow V_F Ultrafast Rectifier, 6 A FRED Pt[®]



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LINKS TO ADDITIONAL RESOURCES



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PRIMARY CHARACTERISTICS							
I _{F(AV)} 6 A							
V _R	600 V						
V _F at I _F	0.98 V						
t _{rr} (typ.)	34 ns						
T _J max.	175 °C						
Package	SlimDPAK (TO-252AE)						
Circuit configuration	Single						

FEATURES

- Ultrafast recovery time, extremely low V_{F} and soft recovery
- For PFC CCM operation
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified

- Automotive ordering code: base P/NHM3, meets JESD 201 class 2 whisker test

• Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters, or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _C = 158 °C	6	٨		
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$, 10 ms sine pulse wave	80	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward valtage	V	I _F = 6 A	-	1.15	1.35	V
Forward voltage V _F	I _F = 6 A, T _J = 150 °C	-	0.98	1.15		
Reverse leakage current		$V_{R} = V_{R}$ rated	-	-	5	
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	125	μΑ
Junction capacitance	CT	V _R = 600 V	-	10	-	pF

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COMPLIANT HALOGEN

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50$	0 A/µs, V _R = 30 V	-	45	-	
		$I_F = 1 \text{ A}, dI_F/dt = 10$	00 A/µs, V _R = 30 V	-	34	-	1
Reverse recovery time	t _{rr}	I _F = 0.5 A, I _R = 1 A, I _{RR} = 0.25 A		-	-	50	ns
		T _J = 25 °C	I _F = 6 A dI _F /dt = 500 A/μs V _R = 400 V	-	65	-	
		T _J = 125 °C		-	90	-	
Book recovery current	1	T _J = 25 °C		-	9.5	-	A
Peak recovery current	I _{RRM}	T _J = 125 °C		-	13.5	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	320	-	nC
		T _J = 125 °C		-	620	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to mount	R _{thJM}		-	-	2.5	°C/W	
Weight			-	0.20	-	g	
Marking device		Case style SlimDPAK (TO-252AE)		6EV	′L06		

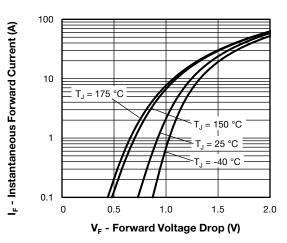


Fig. 1 - Typical Forward Voltage Drop Characteristics

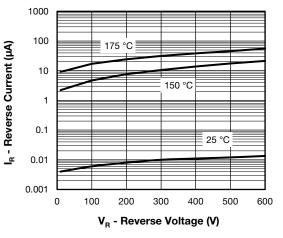
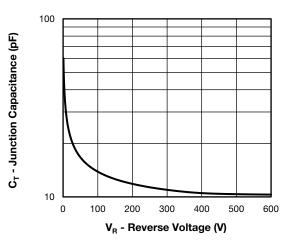


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





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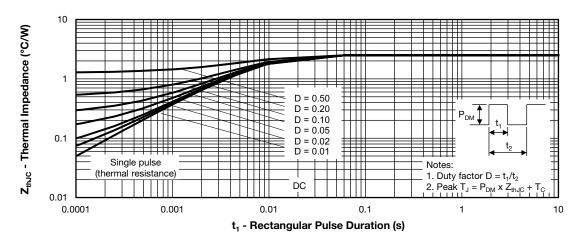
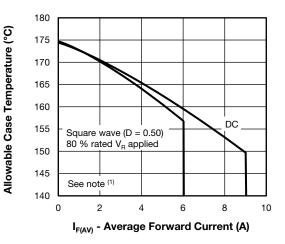


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

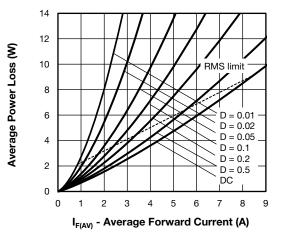


Fig. 6 - Forward Power Loss Characteristics

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{I} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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150 125 °C 130 \mathbf{t}_{rr} (ns) 110 25 °C 90 70 50 100 200 300 400 500 dl_F/dt (A/µs)

Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

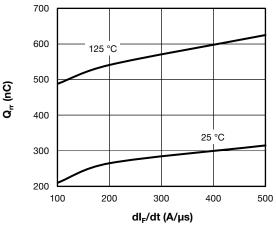
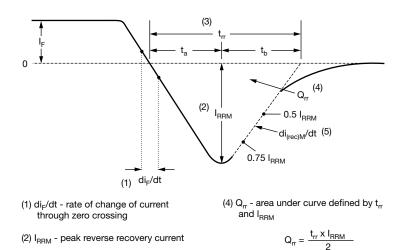


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	VS-	6	Е	v	L	06	н	М3
		2	3	4	5	6	7	8
	1 - 2 - 3 - 4 - 5 - 6 -	- Cur - Circ E = - V = - Pro L = - Volt	rent rati cuit conf single c SlimDP cess typ ultralow tage coo	PAK be: v V _F ultra de (06 =	6 A) n: afast rec 600 V)			
	7 - 8 -	- Env	vironmer	101 qua ntal digit en-free,	:	complia	nt and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-6EVL06HM3/I	0.20	Ι	4500	13"diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96081				
Part marking information	www.vishay.com/doc?96085				
Packaging information	www.vishay.com/doc?88869				

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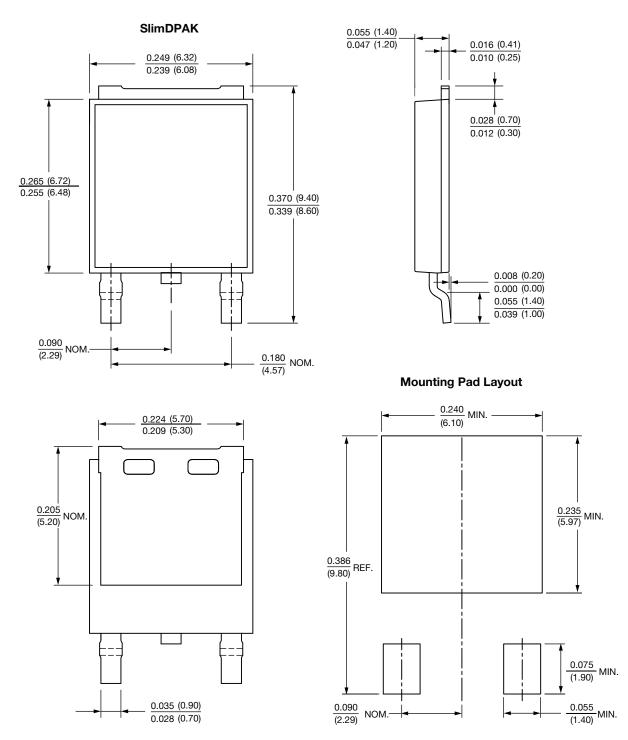


Outline Dimensions

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SlimDPAK

DIMENSIONS in inches (millimeters)



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